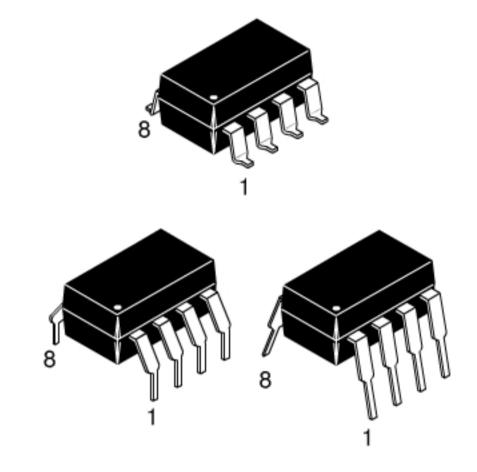


SINGLE-CHANNEL	DUAL-CHANNEL
6N137	HCPL-2630
HCPL-2601	HCPL-2631
HCPL-2611	

### DESCRIPTION

The 6N137, HCPL-2601/2611 single-channel and HCPL-2630/2631 dual-channel optocouplers consist of a 850 nm AlGaAS LED, optically coupled to a very high speed integrated photodetector logic gate with a strobable output. This output features an open collector, thereby permitting wired OR outputs. The coupled parameters are guaranteed over the temperature range of -40 ℃ to +85 ℃. A maximum input signal of 5 mA will provide a minimum output sink current of 13 mA (fan out of 8).

An internal noise shield provides superior common mode rejection of typically 10 kV/ $\mu$ s. The HCPL- 2601 and HCPL- 2631 has a minimum CMR of 5 kV/ $\mu$ s. The HCPL-2611 has a minimum CMR of 10 kV/ $\mu$ s.

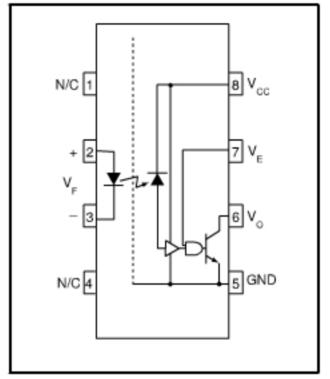


### **FEATURES**

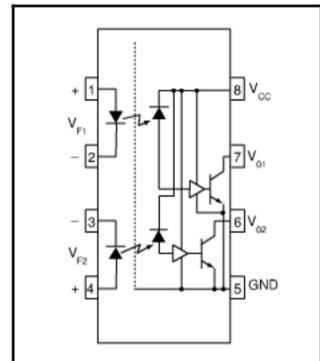
- · Very high speed-10 MBit/s
- Superior CMR-10 kV/μs
- Double working voltage-480V
- Fan-out of 8 over -40 ℃ to +85 ℃
- Logic gate output
- Strobable output
- Wired OR-open collector
- U.L. recognized (File # E90700)

### APPLICATIONS

- · Ground loop elimination
- LSTTL to TTL, LSTTL or 5-volt CMOS
- · Line receiver, data transmission
- Data multiplexing
- · Switching power supplies
- Pulse transformer replacement
- · Computer-peripheral interface



Single-channel circuit drawing



Dual-channel circuit drawing

## TRUTH TABLE (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н

A 0.1  $\mu F$  bypass capacitor must be connected between pins 8 and 5. (See note 1)



SINGLE-CHANNEL 6N137 HCPL-2601 HCPL-2611 DUAL-CHANNEL HCPL-2630 HCPL-2631

ABSOLUTE MAXIMUM RATINGS (No derating required up to 85℃)				
Parameter		Symbol	Value	Units
Storage Temperature		T <sub>STG</sub>	-55 to +125	°C
Operating Temperature		T <sub>OPR</sub>	-40 to +85	∾
Lead Solder Temperature		T <sub>SOL</sub>	260 for 10 sec	°C
EMITTER DC/Average Forward Single channel		I <sub>F</sub>	50	mA
Input Current	Dual channel (Each channel)	1	30	
Enable Input Voltage Single channel  Not to exceed V <sub>CC</sub> by more than 500 mV		V <sub>E</sub>	5.5	V
Reverse Input Voltage	Each channel	V <sub>R</sub>	5.0	V
Power Dissipation Single channel  Dual channel (Each channel)		Б	100	\A/
		- P <sub>I</sub>	45	mW
DETECTOR Supply Voltage		V <sub>CC</sub> (1 minute max)	7.0	٧
Output Current	Single channel		50	т Л
	Dual channel (Each channel)	- I <sub>0</sub>	50	mA
Output Voltage	Each channel	V <sub>O</sub>	7.0	V
Collector Output	Single channel	ь	85	m\\\
Power Dissipation	Dual channel (Each channel)	- P <sub>O</sub>	60	mW

RECOMMENDED OPERATING CONDITIONS				
Parameter	Symbol	Min	Max	Units
Input Current, Low Level	I <sub>FL</sub>	0	250	μΑ
Input Current, High Level	I <sub>FH</sub>	*6.3	15	mA
Supply Voltage, Output	V <sub>CC</sub>	4.5	5.5	V
Enable Voltage, Low Level	V <sub>EL</sub>	0	0.8	V
Enable Voltage, High Level	V <sub>EH</sub>	2.0	V <sub>CC</sub>	V
Low Level Supply Current	T <sub>A</sub>	-40	+85	℃
Fan Out (TTL load)	N		8	

<sup>\* 6.3</sup> mA is a guard banded value which allows for at least 20 % CTR degradation. Initial input current threshold value is 5.0 mA or less



SINGLE-CHANNEL

6N137 HCPL-2601 HCPL-2630 HCPL-2631

DUAL-CHANNEL

HCPL-2611

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = -40 ℃ to +85 ℃ Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS							
Parameter		Test Conditions	Symbol	Min	Typ**	Max	Unit
EMITTER		$(I_F = 10 \text{ mA})$	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \			1.8	.,
Input Forward Voltage		T <sub>A</sub> =25 °C	V <sub>F</sub>		1.4	1.75	V
Input Reverse Breakdown V	oltage/	$(I_R = 10 \mu A)$	B <sub>VR</sub>	5.0			٧
Input Capacitance		$(V_F = 0, f = 1 MHz)$	C <sub>IN</sub>		60		pF
Input Diode Temperature Co	efficient	$(I_F = 10 \text{ mA})$	$\Delta V_F / \Delta T_A$		-1.4		mV/℃
DETECTOR					7	10	
High Level Supply Current	Single Channel	$(V_{CC} = 5.5 \text{ V}, I_F = 0 \text{ mA})$	I <sub>CCH</sub>		7	10	mA
	Dual Channel	$(V_E = 0.5 V)$			15	20	
Low Level Supply Current	Single Channel	$(V_{CC} = 5.5 \text{ V}, I_F = 10 \text{ mA})$			9	13	A
	Dual Channel	$(V_E = 0.5 V)$	ICCL		19	26	mA
Low Level Enable Current		$(V_{CC} = 5.5 \text{ V}, V_{E} = 0.5 \text{ V})$	I <sub>EL</sub>		-0.8	-1.6	mA
High Level Enable Current		$(V_{CC} = 5.5 \text{ V}, V_{E} = 2.0 \text{ V})$	I <sub>EH</sub>		-0.6	-1.6	mA
High Level Enable Voltage		$(V_{CC} = 5.5 \text{ V}, I_F = 10 \text{ mA})$	V <sub>EH</sub>	2.0			٧
Low Level Enable Voltage	(V <sub>CC</sub> =	5.5 V, I <sub>F</sub> = 10 mA) (Note 3)	V <sub>EL</sub>			0.8	V

SWITCHING CHARACTERISTICS (T <sub>A</sub> = -40 °C to +85 °C, V <sub>CC</sub> = 5 V, I <sub>F</sub> = 7.5 mA Unless otherwise specified.)					
AC Characteristics Test Conditions	Symbol	Min	Typ**	Max	Unit
Propagation Delay Time (Note 4) (T <sub>A</sub> =25 ℃)		20	45	75	
to Output High Level (R <sub>L</sub> = 350 $\Omega$ , C <sub>L</sub> = 15 pF) (Fig. 12)	T <sub>PLH</sub>			100	ns
Propagation Delay Time (Note 5) (T <sub>A</sub> =25 ℃)	_	25	45	75	
to Output Low Level (R <sub>L</sub> = 350 $\Omega$ , C <sub>L</sub> = 15 pF) (Fig. 12)	T <sub>PHL</sub>			100	ns
Pulse Width Distortion (R <sub>L</sub> = 350 $\Omega$ , C <sub>L</sub> = 15 pF) (Fig. 12)	T <sub>PHL</sub> -T <sub>PLH</sub>		3	35	ns
Output Rise Time (10-90%) $(R_L = 350 \ \Omega, \ C_L = 15 \ pF)$ (Note 6) (Fig. 12)	t <sub>r</sub>		50		ns
Output Fall Time (90-10%) $(R_L = 350 \ \Omega, \ C_L = 15 \ pF)$ (Note 7) (Fig. 12)	t <sub>f</sub>		12		ns
Enable Propagation Delay Time $(I_F = 7.5 \text{ mA}, V_{EH} = 3.5 \text{ V})$ to Output High Level $(R_L = 350 \ \Omega, C_L = 15 \text{ pF})$ (Note 8) (Fig. 13)	telh		20		ns
Enable Propagation Delay Time $(I_F = 7.5 \text{ mA}, V_{EH} = 3.5 \text{ V})$ to Output Low Level $(R_L = 350 \ \Omega, C_L = 15 \text{ pF})$ (Note 9) (Fig. 13)	t <sub>EHL</sub>		20		ns
Common Mode Transient Immunity $(T_A = 25  ^\circ \! C)  V_{CM}  = 50  V$ , (Peak) (at Output High Level) $(I_F = 0  \text{mA},  V_{OH}  (\text{Min.}) = 2.0  V)$ 6N137, HCPL-2630 $(R_L = 350  \Omega)$ (Note 10) HCPL-2601, HCPL-2631 (Fig. 14)	CM <sub>H</sub>	5000	10,000 10,000		V/µs
HCPL-2611  V <sub>CM</sub>   = 400 V		10,000	15,000		
$ (R_{L} = 350 \ \Omega) \ (I_{F} = 7.5 \ mA, \ V_{OL} \ (Max.) = 0.8 \ V) $ Common Mode $ 6N137, \ HCPL-2630 \qquad  V_{CM}  = 50 \ V \ (Peak) $			10,000		W
Transient Immunity HCPL-2601, HCPL-2631 (T <sub>A</sub> =25 ℃) (at Output Low Level) (Note 11) (Fig. 14)	CM <sub>L</sub>	5000	10,000		V/µs
HCPL-2611 (T <sub>A</sub> =25 °C)  V <sub>CM</sub>   = 400 V		10,000	15,000		



SINGLE-CHANNEL
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HCPL-2601 HCPL-2631
HCPL-2611

TRANSFER CHARACTERISTICS (T <sub>A</sub> = -40 °C to +85 °C Unless otherwise specified.)						
DC Characteristics	Test Conditions	Symbol	Min	Typ**	Max	Unit
High Level Output Current	$(V_{CC} = 5.5 \text{ V}, V_{O} = 5.5 \text{ V})$	1			100	
	$(I_F = 250 \ \mu\text{A}, \ V_E = 2.0 \ \text{V}) \ (\text{Note 2})$	'ОН			100	μΑ
Low Level Output Current	$(V_{CC} = 5.5 \text{ V}, I_F = 5 \text{ mA})$	V		.35	.06	V
	$(V_E = 2.0 \text{ V}, I_{CL} = 13 \text{ mA}) \text{ (Note 2)}$	V <sub>OL</sub>		.5	.00	<b>v</b>
Input Threshold Current	$(V_{CC} = 5.5 \text{ V}, V_{O} = 0.6 \text{ V},$	I <sub>FT</sub>		3	5	mA
mpat timeeriola darront	$V_E = 2.0 \text{ V}, I_{OL} = 13 \text{ mA})$	<u>.</u> F1		,	J	

ISOLATION CHARACTERISTICS (T <sub>A</sub> = -40 ℃ to +85 ℃ Unless otherwise specified.)						
Characteristics	Test Conditions	Symbol	Min	Typ**	Max	Unit
Input-Output	(Relative humidity = 45%)					
Insulation Leakage Current	$(T_A = 25 {}^{\circ}\!C, t = 5 s)$				1.0*	
	$(V_{I-O} = 3000 \text{ VDC})$	I <sub>I-O</sub>			1.0*	μΑ
	(Note 12)					
Withstand Insulation Test Voltage	(RH < 50%, T <sub>A</sub> = 25℃)	V	2500			\/
	(Note 12) ( $t = 1 \text{ min.}$ )	V <sub>ISO</sub>	2500			V <sub>RMS</sub>
Resistance (Input to Output)	$(V_{I-O} = 500 \text{ V}) \text{ (Note 12)}$	R <sub>I-O</sub>		10 <sup>12</sup>		Ω
Capacitance (Input to Output)	(f = 1 MHz) (Note 12)	C <sub>I-O</sub>		0.6		pF

<sup>\*\*</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C

### **NOTES**

- The V<sub>CC</sub> supply to each optoisolator must be bypassed by a 0.1µF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V<sub>CC</sub> and GND pins of each device.
- 2. Each channel.
- 3. Enable Input No pull up resistor required as the device has an internal pull up resistor.
- t<sub>PLH</sub> Propagation delay is measured from the 3.75 mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- t<sub>PHL</sub> Propagation delay is measured from the 3.75 mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- 6.  $t_r$  Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- 7. t<sub>f</sub> Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- t<sub>ELH</sub> Enable input propagation delay is measured from the 1.5 V level on the HIGH to LOW transition of the input voltage pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- t<sub>EHL</sub> Enable input propagation delay is measured from the 1.5 V level on the LOW to HIGH transition of the input voltage pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- CM<sub>H</sub> The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the high state (i.e., V<sub>OUT</sub> > 2.0 V). Measured in volts per microsecond (V/μs).
- CM<sub>L</sub> The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the low output state (i.e., V<sub>OUT</sub> < 0.8 V). Measured in volts per microsecond (V/μs).</li>
- 12. Device considered a two-terminal device: Pins 1,2,3 and 4 shorted together, and Pins 5,6,7 and 8 shorted together.



SINGLE-CHANNEL 6N137 HCPL-2601 HCPL-2611

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Fig.1 Low Level Output Voltage vs. Ambient Temperature

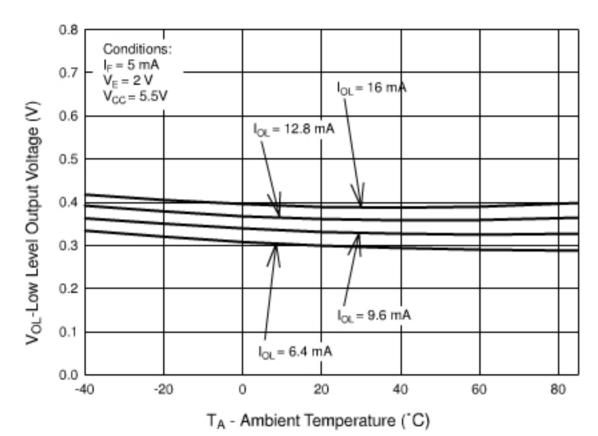
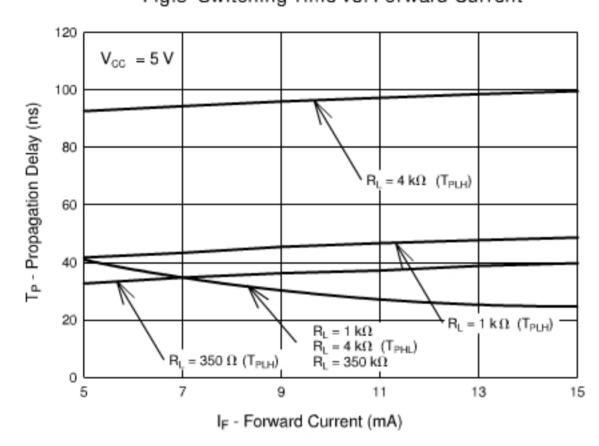


Fig.3 Switching Time vs. Forward Current



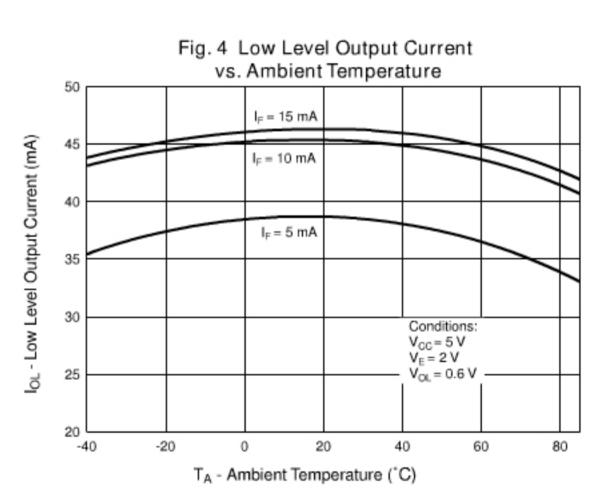


Fig. 5 Input Threshold Current

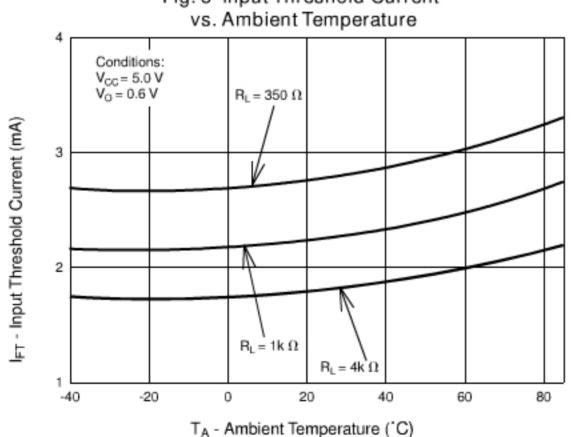
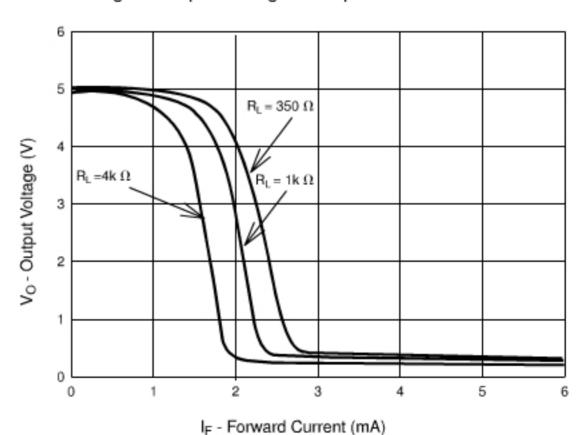


Fig. 6 Output Voltage vs. Input Forward Current





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Fig. 7 Pulse Width Distortion vs. Temperature

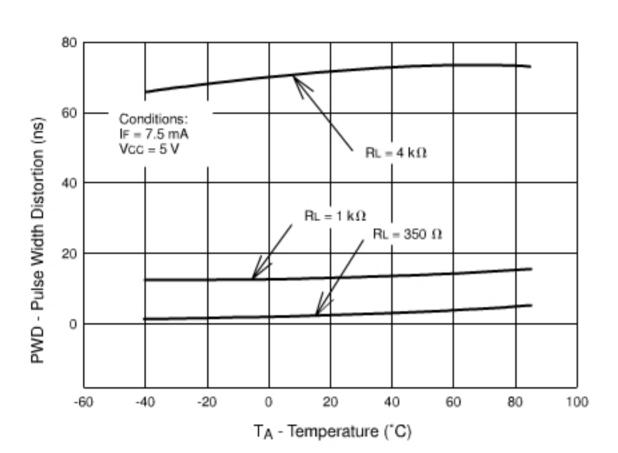


Fig. 8 Rise and Fall Time vs. Temperature

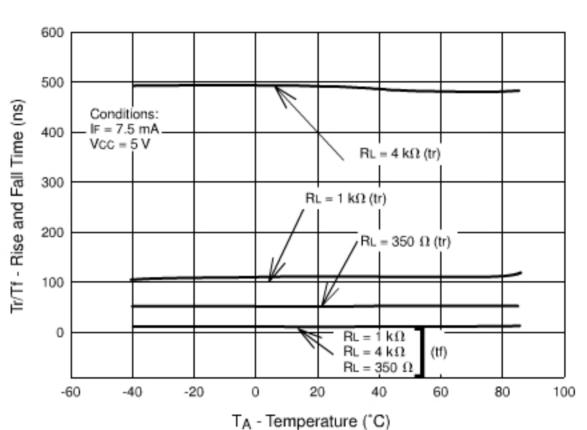


Fig. 9 Enable Propagation Delay vs. Temperature

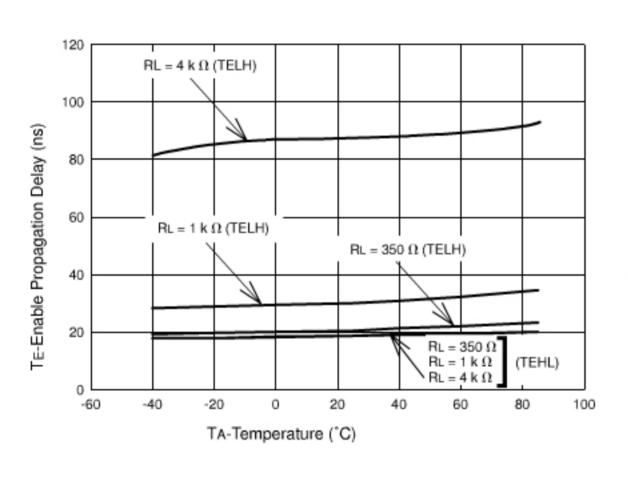


Fig. 10 Switching Time vs. Temperature

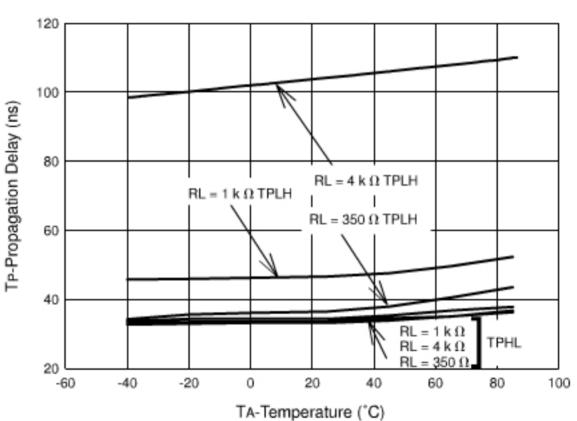
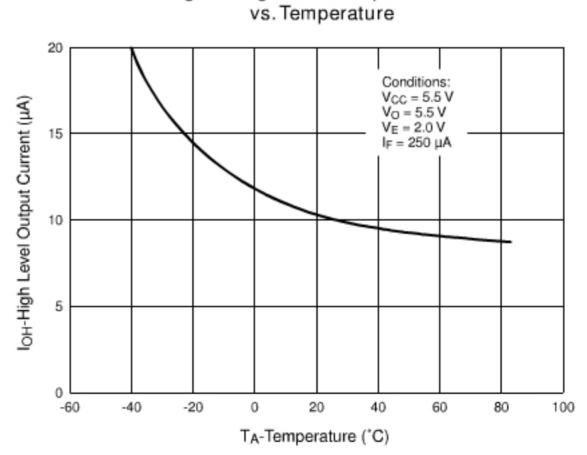


Fig. 11 High Level Output Current





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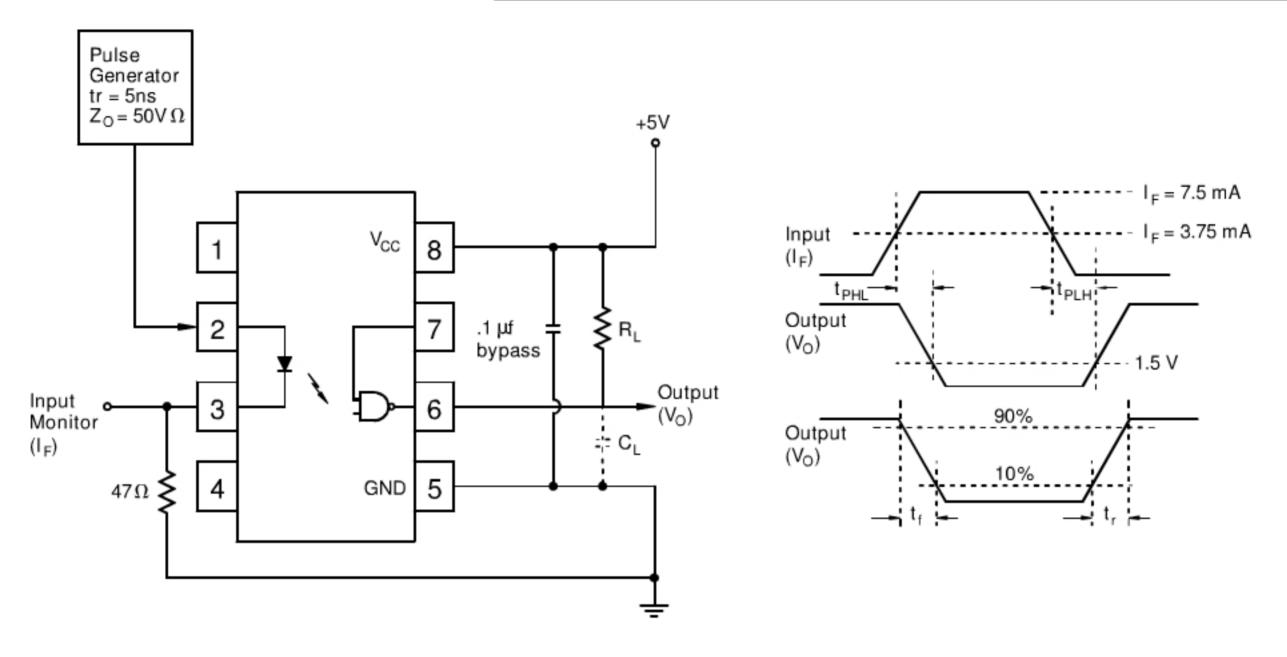


Fig. 12 Test Circuit and Waveforms for  $t_{\text{PLH}},\,t_{\text{PHL}_1}\,t_{\text{r}}$  and  $t_{\text{f}}.$ 

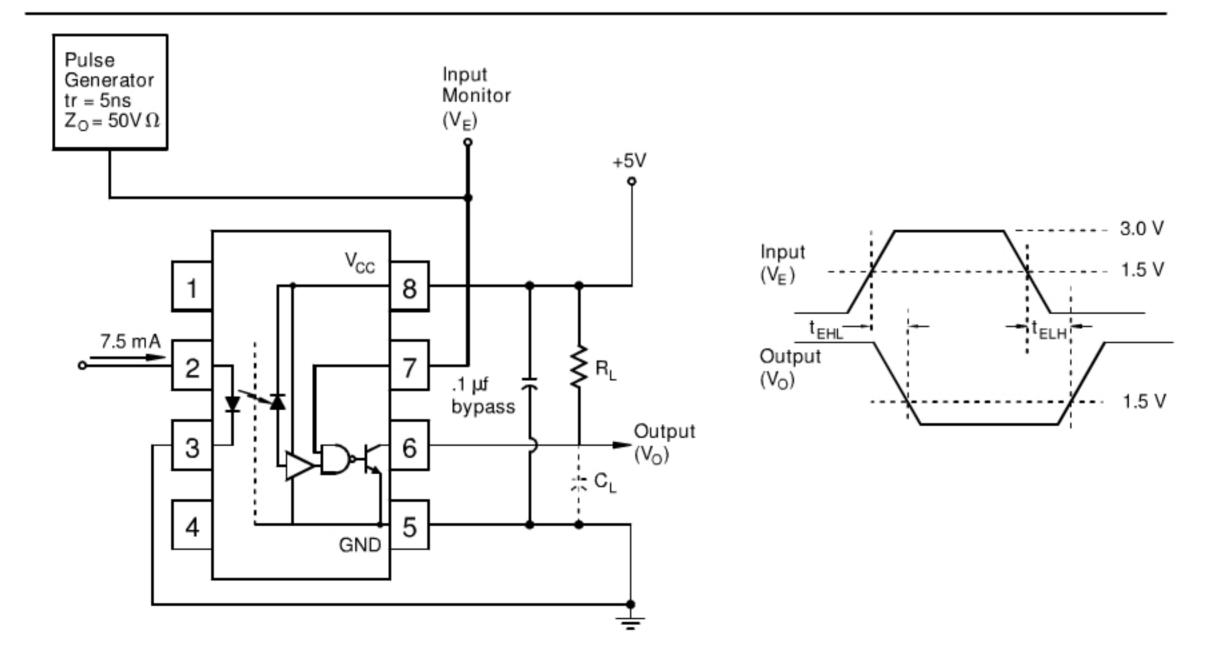


Fig. 13 Test Circuit t<sub>EHL</sub> and t<sub>ELH</sub>.

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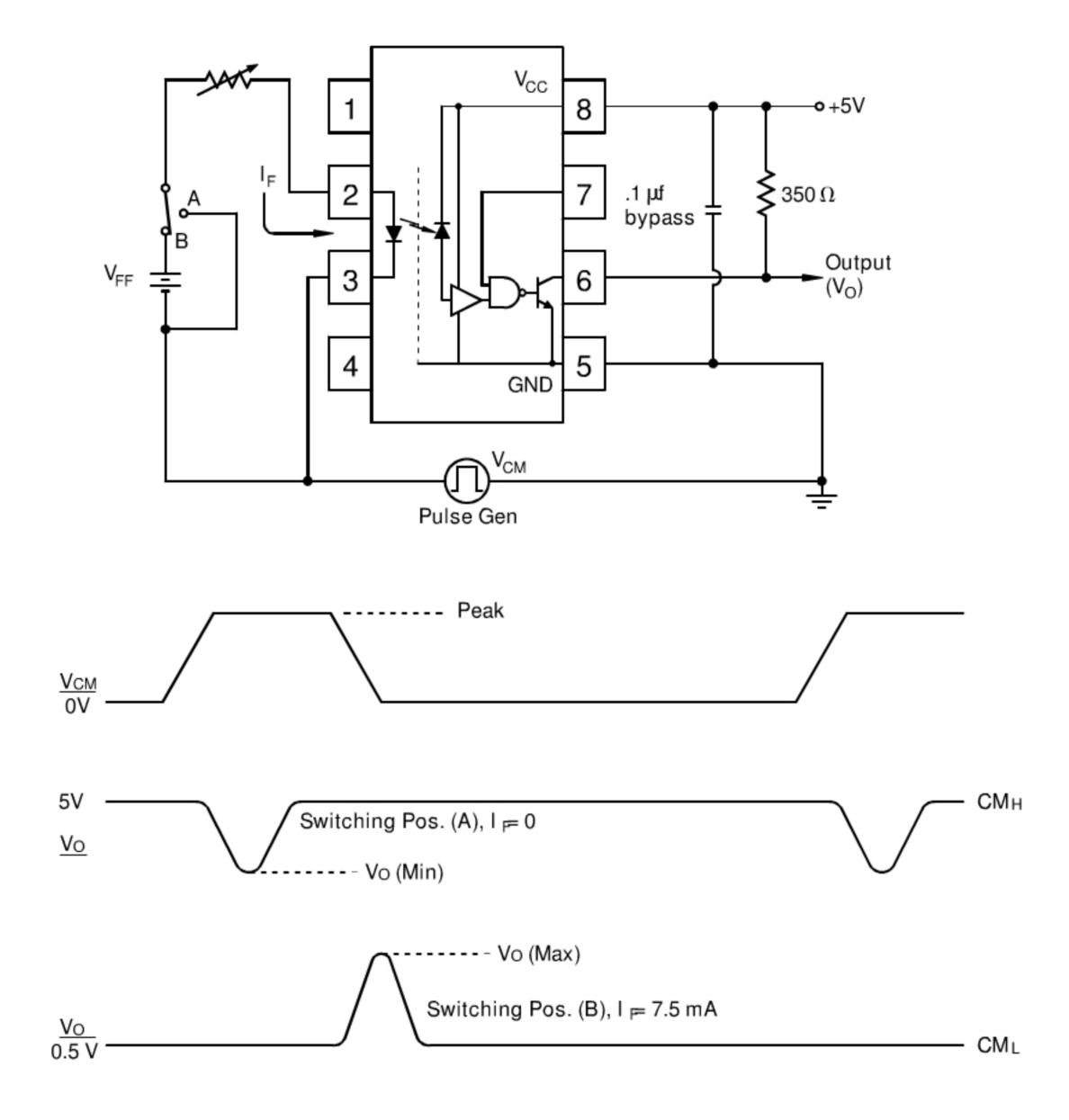
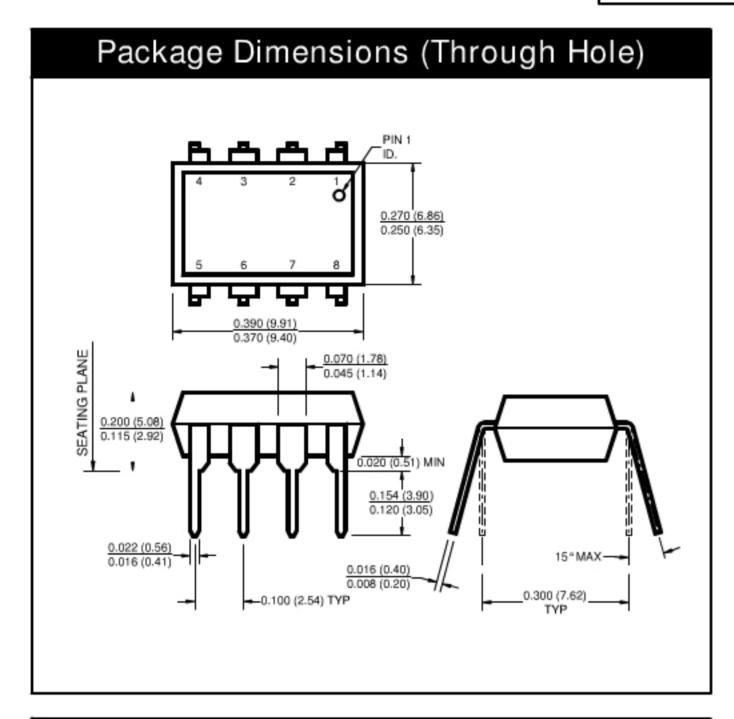
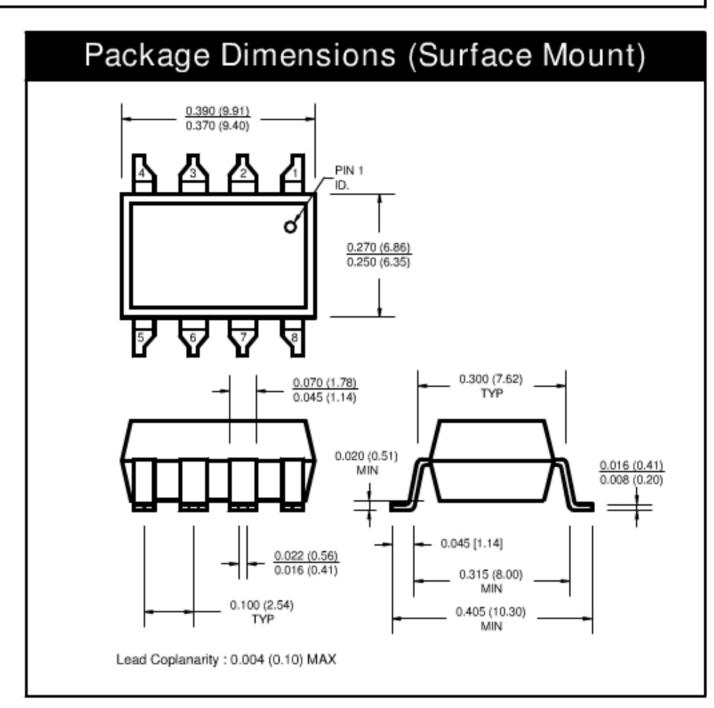


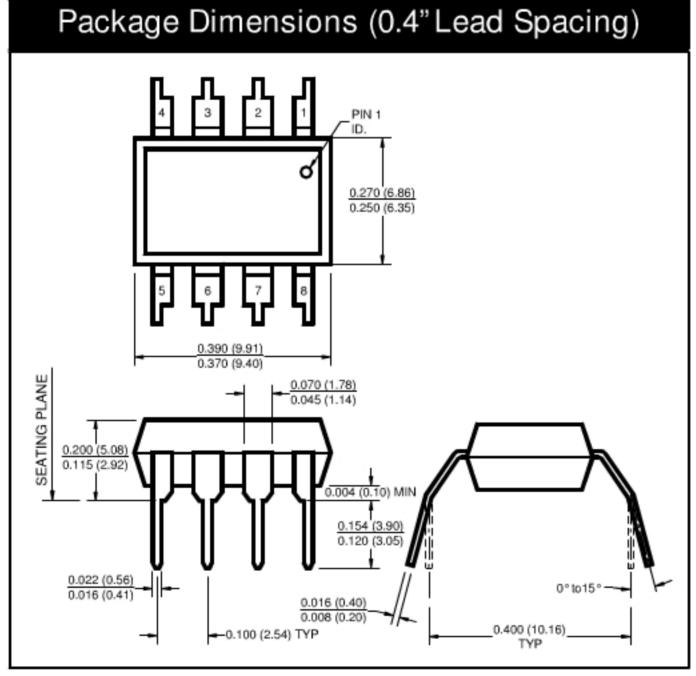
Fig. 14 Test Circuit Common Mode Transient Immunity



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NOTE
All dimensions are in inches (millimeters)

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SINGLE-CHANNEL

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HCPL-2601

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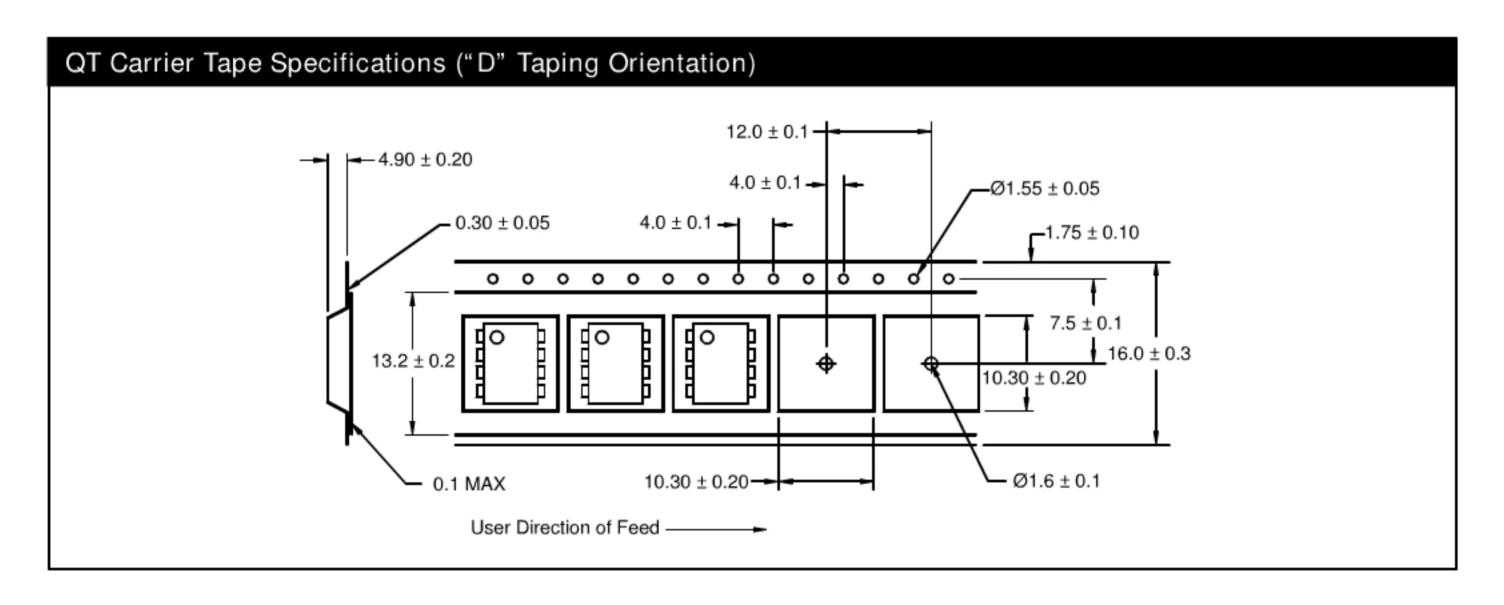
**DUAL-CHANNEL** 

HCPL-2630

HCPL-2631

### ORDERING INFORMATION

Option	Order Entry Identifier	Description
R2	.R2	Opto Plus Reliability Conditioning
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing



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